

10A Lead Type Super Low Barrier Diode

■ Features

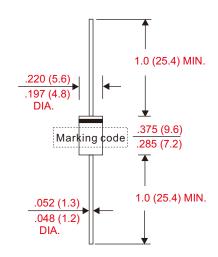
- Axial lead type devices for through hole design.
- · Low forward voltage drop.
- Excellent high temperature stability.
- · Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSRS10100G.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case: Molded plastic, DO-201AD / DO-27
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity: Color band denotes cathode end
- Weight: Approximated 1.10 gram

■ Outline

DO-27(DO-201AD)



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CSRS10100	UNIT
Marking code			CSRS10100	
Peak repetitive reverse voltage		V _{RRM}		
Working peak reverse voltage		V_{RWM}	100	V
DC blocking voltage		V _{RM}		
Forward rectified current		Io	10	Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	200	А
Peak repetitive reverse surge current	2us - 1kHz	I _{RRM}	3	Α
Thermal resistance	Junction to ambient	R _{eJA}	73	°C/W
Operating and Storage temperature		T _J , T _{STG}	-65 ~ +175	°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage drop	I _F = 10A, T _J = 25°C	V _F			700	mV
	$I_F = 10A, T_J = 125^{\circ}C$			570	630	
	$I_F = 20A, T_J = 25^{\circ}C$				820	
Reverse current	$V_R = V_{RRM} T_J = 25^{\circ}C$	- I _R			0.5	mA
	$V_R = V_{RRM} T_J = 125^{\circ}C$				25	

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■ Rating and characteristic curves

Fig.1 - Forward Current Derating Curve

(4)

10

10

2

- single phase half wave 60Hz

resistive or inductive load

0

25

50

75

100

125

150

175

Ambient Temperature, T_A (°C)

Fig. 2 - Instantaneous Forward Characteristics

100

T_A=150°C

T_A=150°C

1

T_A=100°C

T_A=25°C

1

0.01

0.1

0.2

0.3

0.4

0.5

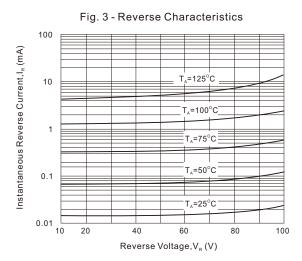
0.6

0.7

0.8

0.9

Instantaneous Forward Voltage, V_F (Volts)



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